Octal D-Type Flip-Flop with 3-State Outputs

The MC74ACT564 is a high-speed, low power octal flip-flop with a buffered common Clock (CP) and a buffered common Output Enable (\overline{OE}).

The information presented to the D inputs is stored in the flip-flops on the LOW-to-HIGH Clock (CP) transition.

The MC74ACT564 device is functionally indentical to the MC74ACT574, but with inverted outputs.

Features

- Inputs and Outputs on the Opposite Sides of the Package Allowing Easy Interface with Microprocessors
- Useful as Input or Output Port for Microprocessor
- Functionally Indentical to the MC74ACT574 but with Inverted Outputs
- 3-State Outputs for Bus-Oriented Applications
- Outputs Source/Sink 24 mA
- TTL Compatible Inputs
- These are Pb-Free Devices

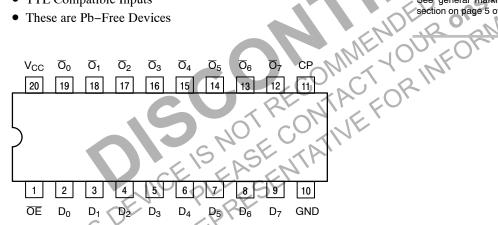


Figure 1. Pinout: 20-Lead Packages Conductors (Top View)

PIN ASSIGNMENT

PIN	FUNCTION
D ₀ -D ₇	Data Inputs
СР	Clock Pulse Input
ŌĒ	3-State Output Enable Input
$\overline{O}_0-\overline{O}_7$	3-State Outputs



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SOIC-20W **DW SUFFIX** CASE 751D

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

DEVICE MARKING INFORMATION

See general marking information in the device marking section on page 5 of this data sheet.

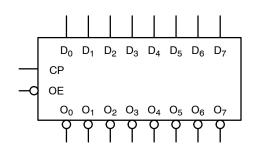
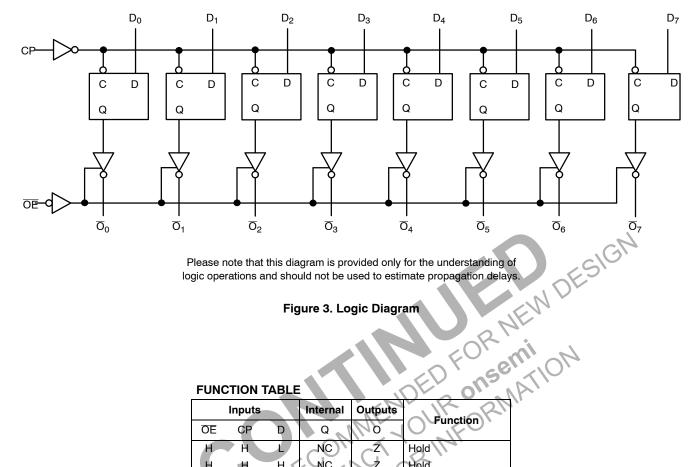


Figure 2. Logic Symbol



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Figure 3. Logic Diagram

FUNCTION TABLE

Inputs	Internal	Outputs	Function
OE CP D	Q	100 7	Punction
HHL	NC	Z	Hold
H H H	NC	Z (Hold
H J J	H	Z	Load
) н 'Ф ₎ н С	OL, 1	Z	Load
L 1	- H()	Н	Data Available
TOH,	L	L	Data Available
L H L	NC	NC	No Change in Data
F H H	NC	NC	No Change in Data

HIGH Voltage Level LOW Voltage Level

Immaterial

High Impedance

LOW-to-HIGH Transition

No Change

FUNCTIONAL DESCRIPTION

The MC74ACT564 consists of eight edge-triggered flip-flops with individual D-type inputs and 3-state complementary outputs. The buffered clock and buffered Output Enable are common to all flip-flops. The eight flip-flops will store the state of their individual D inputs that

meet the setup and hold times requirements on the LOW-to-HIGH Clock (CP) transition. With the Output Enable (OE) LOW, the contents of the eight flip-flops are available at the outputs. When \overline{OE} is HIGH, the outputs go to the high impedance state. Operation of the \overline{OE} input does not affect the state of the flip-flops.

MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{CC}	DC Supply Voltage (Referenced to GND)	-0.5 to +7.0	V
V _{IN}	DC Input Voltage (Referenced to GND)	-0.5 to V _{CC} +0.5	V
V _{OUT}	DC Output Voltage (Referenced to GND) (Note 1)	-0.5 to V _{CC} +0.5	V
I _{IK}	DC Input Diode Current	±20	mA
I _{OK}	DC Output Diode Current	±50	mA
I _{OUT}	DC Output Sink/Source Current	±50	mA
Icc	DC Supply Current, per Output Pin	±50	mA
I _{GND}	DC Ground Current, per Output Pin	±100	mA
T _{STG}	Storage Temperature Range	-65 to +150	°C
T_L	Lead temperature, 1 mm from Case for 10 Seconds	260	°C
T_J	Junction Temperature Under Bias	140	°C
$\theta_{\sf JA}$	Thermal Resistance (Note 2)	65.8	°C/W
MSL	Moisture Sensitivity	Level 1	
F_R	Flammability Rating Oxygen Index: 30% – 3	5% UL 94 V-0 @ 0.125 in	
V _{ESD}	ESD Withstand Voltage Human Body Model (Note Machine Model (Note Charged Device Model (Note	> 200	V
I _{Latchup}	Latchup Performance Above V _{CC} and Below GND at 85°C (Note	e 6) ±100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. I_{OUT} absolute maximum rating must be observed.

2. The package thermal impedance is calculated in accordance with JESD 51–7.

3. Tested to EIA/JESD22–A114–A.

4. Tested to EIA/JESD22–C101–A.

6. Tested to EIA/JESD78.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	DC Input Voltage (Referenced to GND)	4.5		5.5	V
V _{in} , V _{out}	DC Input Voltage, Output Voltage (Referenced to GND)	0		V _{CC}	٧
T _A	Operating Temperature, All Package Types	-40	25	+85	°C
t _r , t _f	Input Rise and Fall Time (Note 8) $ V_{CC} = 4.5 \text{ V} $	0	10 8.0	10 8.0	ns/V
I _{OH}	Output Current – High			-24	mA
I _{OL}	Output Current – Low			24	mA

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

- 7. Unused Inputs may not be left open. All inputs must be tied to a high voltage level or low logic voltage level.
- 8. V_{in} from 0.8 V to 2.0 V; refer to individual Data Sheets for devices that differ from the typical input rise and fall times.

DC CHARACTERISTICS

		V _{CC}	T _A = +	+25°C	T _A = -40°C to +85°C		
Symbol	Parameter	(V)	Тур	Gua	ranteed Limits	Unit	Conditions
V _{IH}	Minimum High Level Input Voltage	4.5 5.5	1.5 1.5	2.0 2.0	2.0 2.0	V	V _{OUT} = 0.1 V or V _{CC} - 0.1 V
V _{IL}	Maximum Low Level Input Voltage	4.5 5.5	1.5 1.5	0.8 0.8	0.8 0.8	V	V _{OUT} = 0.1 V or V _{CC} - 0.1 V
V _{OH}	Minimum High Level Output Voltage	4.5 5.5	4.49 5.49	4.4 5.4	4.4 5.4	V V	I _{OUT} = -50 μA
		4.5 5.5		3.86 4.86	3.76 4.76	V V	$^{*}V_{IN} = V_{IL} \text{ or } V_{IH}$ -24 mA -24 mA
V _{OL}	Maximum Low Level Output Voltage	4.5 5.5	0.001 0.001	0.1 0.1	0.1 0.1	V	I _{OUT} = 50 μA
		4.5 5.5		0.36 0.36	0.44 0.44	V	*V _{IN} = V _{IL} or V _{IH} 24 mA loL 24 mA
I _{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μΑ	V _I = V _{CC} , GND
ΔI_{CCT}	Additional Max. I _{CC} /Input	5.5	0.6		1.5	mA	V _I = V _{CC} – 2.1 V
l _{OZ}	Maximum 3-State Current	5.5		±0.5	±5.0	μA	$\begin{aligned} & V_{I}\left(OE\right) = V_{IL}, V_{IH} \\ & V_{I} = V_{CC}, GND \\ & V_{O} = V_{CC}, GND \end{aligned}$
I _{OLD} I _{OHD}	†Minimum Dynamic Output Current	5.5 5.5	1		75 -75	mA mA	V _{OLD} = 1.65 V Max V _{OHD} = 3.85 V Min
I _{CC}	Maximum Quiescent Supply Current	5.5		8.0	80	μA	V _{IN} = V _{CC} or GND

^{*}All outputs loaded; thresholds on input associated with output under test. †Maximum test duration 2.0 ms, one output loaded at a time.

AC CHARACTERISTICS $t_r = t_f = 3.0$ ns (For Figures and Waveforms, See Figures 4, 5, and 6.)

Symbol	Symbol Parameter C			Γ _A = +25°C C _L = 50 pF	:		C to +85°C 50 pF	Unit
	CHOLO	(v)	Min	Тур	Max	Min	Max	
f _{max}	Maximum Clock Frequency	5.0	85	-	-	75	-	MHz
t _{PLH}	Propagation Delay CP to \overline{Q}_{n}	5.0	2.0	-	10.5	1.5	11.5	ns
t _{PHL}	Propagation Delay ${\sf CP}$ to ${\sf \overline{Q}}_{\sf n}$	5.0	1.5	-	9.5	1.5	10.5	ns
t _{PZH}	Output Enable Time	5.0	1.5	-	9.0	1.5	9.5	ns
t _{PZL}	Output Enable Time	5.0	1.5	-	8.5	1.0	9.5	ns
t _{PHZ}	Output Disable Time	5.0	1.5	-	10.5	1.5	11.5	ns
t _{PLZ}	Output Disable Time	5.0	1.5	-	8.0	1.0	8.5	ns

^{*}Voltage Range 5.0 V is 5.0 V \pm 0.5 V

AC OPERATING REQUIREMENTS

Symbol	Parameter		V _{CC} * (V)	7	Γ _A = +25°C C _L = 50 pF	T _A = -40°C to +85°C C _L = 50 pF	Unit
			(*)	Typ Guaranteed Minimum			
t _s	Setup Time, HIGH or LOW	D _n to C _P	5.0	_	2.5	3.0	ns
t _h	Hold Time, HIGH or LOW	D _n to C _P	5.0	_	1.0	1.0	ns
t _w	C _P Pulse Width	HIGH or LOW	5.0	-	3.0	3.5	ns

^{*}Voltage Range 3.3 V is 3.3 V ± 0.3 V.

CAPACITANCE

Symbol	Parameter	Value Typ	Unit	Test Conditions
C _{IN}	Input Capacitance	4.5	pF	V _{CC} = 5.0 V
C _{PD}	Power Dissipation Capacitance	50	pF	V _{CC} = 5.0 V

ORDERING INFORMATION

Device	Package	Shipping [†]
MC74ACT564DWR2G	SOIC-20 (Pb-Free)	1000 / Tape & Reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MARKING DIAGRAMS

SOIC-20W

20 H H H H H H H H H

ACT564 AWLYYWWG

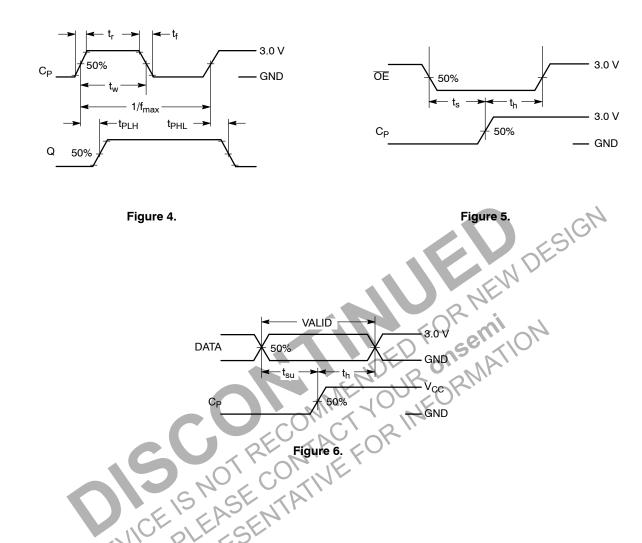
A = Assembly Location

WL = Wafer Lot
 YY = Year
 WW = Work Week
 G = Pb-Free Package

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^{*}Voltage Range 5.0 V is 5.0 V ±0.5 V.

SWITCHING WAVEFORMS



*Includes all probe and jig capacitance

DEVICE UNDER

TEST

Figure 7. Test Circuit

OUTPUT

450 Ω

 C_L^*

50 Ω SCOPE TEST POINT

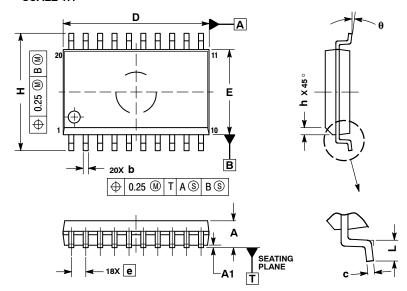




SOIC-20 WB CASE 751D-05 **ISSUE H**

DATE 22 APR 2015

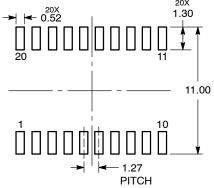
SCALE 1:1



- DIMENSIONS ARE IN MILLIMETERS.
 INTERPRET DIMENSIONS AND TOLERANCES.
- PER ASME Y14.5M, 1994.
 3. DIMENSIONS D AND E DO NOT INCLUDE MOLD
- PROTRUSION.
 MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
- DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF B DIMENSION AT MAXIMUM MATERIAL

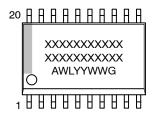
	MILLIMETERS					
DIM	MIN	MAX				
Α	2.35	2.65				
A1	0.10	0.25				
b	0.35	0.49				
С	0.23	0.32				
D	12.65	12.95				
E	7.40	7.60				
е	1.27	BSC				
Н	10.05	10.55				
h	0.25	0.75				
L	0.50	0.90				
A	0 °	7 °				

RECOMMENDED **SOLDERING FOOTPRINT***



DIMENSIONS: MILLIMETERS

GENERIC MARKING DIAGRAM*



XXXXX = Specific Device Code = Assembly Location

WL = Wafer Lot ΥY = Year WW = Work Week = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

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